# 0IMD9-001

# Product Preview Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is ideal for medical applications where space is limited.

#### Features

- Extremely Fast Switching Speed
- Low Forward Voltage 0.35 V (Typ) @  $I_F = 10 \text{ mAdc}$
- Device Marking: MAM
- AEC Qualified and Built In Medical Flow
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS (T<sub>J</sub> = 125°C unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	30	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, (Note 1)	PD		
$T_A = 25^{\circ}C$ Derate above 25°C		200 1.57	mW mW/°C
Forward Current (DC)	١ <sub>F</sub>	200 Max	mA
Non-Repetitive Peak Forward Current, t <sub>p</sub> < 10 msec	I <sub>FSM</sub>	600	mA
Repetitive Peak Forward Current Pulse Wave = 1 sec, Duty Cycle = 66%	I <sub>FRM</sub>	300	mA
Thermal Resistance Junction-to-Ambient	$R_{\thetaJA}$	635	°C/W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to150	°C

1. FR-4 Minimum Pad

This document contains information on a product under development. ON Semiconductor reserves the right to change or discontinue this product without notice.



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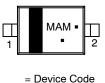
# 30 VOLT SILICON HOT-CARRIER DETECTOR AND SWITCHING DIODES



CASE 477 STYLE 1

1 0 4 0 2 CATHODE ANODE

#### MARKING DIAGRAM



MA = Device Code M = Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
0IMD9-001-XTP	SOD-323 (Pb-Free)	3000 / Tape & Reel

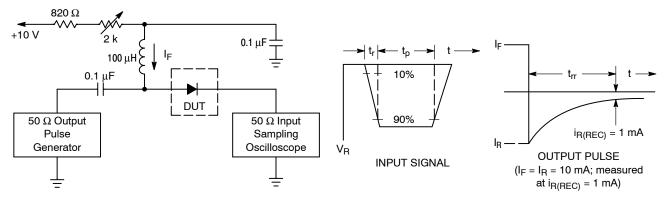
+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I <sub>R</sub> = 10 μA)	V <sub>(BR)R</sub>	30	_	_	V
Total Capacitance (V <sub>R</sub> = 1.0 V, f = 1.0 MHz)	C <sub>T</sub>	-	7.6	10	pF
Reverse Leakage (V <sub>R</sub> = 25 V)	۱ <sub>R</sub>	_	0.5	2.0	μAdc
Forward Voltage (I <sub>F</sub> = 0.1 mAdc)	V <sub>F</sub>	_	0.22	0.24	Vdc
Forward Voltage (I <sub>F</sub> = 30 mAdc)	V <sub>F</sub>	_	0.41	0.5	Vdc
Forward Voltage (I <sub>F</sub> = 100 mAdc)	V <sub>F</sub>	_	0.52	0.8	Vdc
Reverse Recovery Time ( $I_F = I_R = 10$ mAdc, $I_{R(REC)} = 1.0$ mAdc) Figure 1	t <sub>rr</sub>	_	-	5.0	ns
Forward Voltage (I <sub>F</sub> = 1.0 mAdc)	V <sub>F</sub>	_	0.29	0.32	Vdc
Forward Voltage (I <sub>F</sub> = 10 mAdc)	V <sub>F</sub>	-	0.35	0.40	Vdc

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

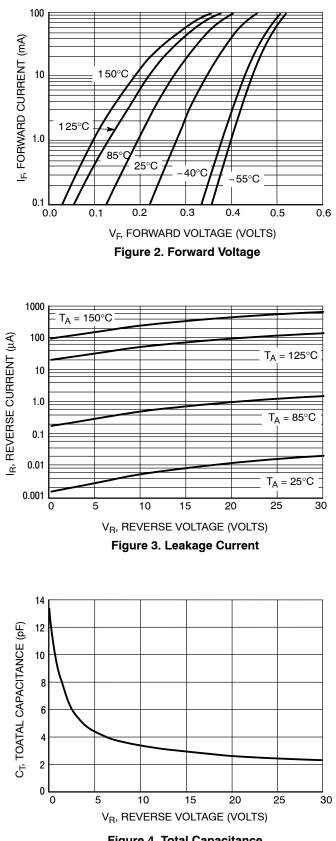
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 10 mA. 2. Input pulse is adjusted so I<sub>R(peak)</sub> is equal to 10 mA. 3. t<sub>p</sub> » t<sub>rr</sub>

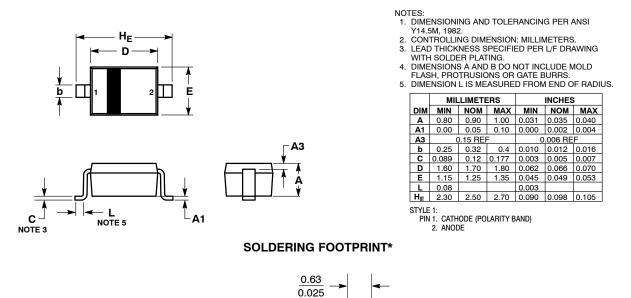
#### Figure 1. Recovery Time Equivalent Test Circuit

### 0IMD9-001



#### PACKAGE DIMENSIONS

SOD-323 CASE 477-02 ISSUE H



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

 $\frac{1.60}{0.063}$  $\frac{2.85}{0.112}$   $\frac{0.83}{0.033}$ 

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